Octal 3-State Inverting Bus Transceiver

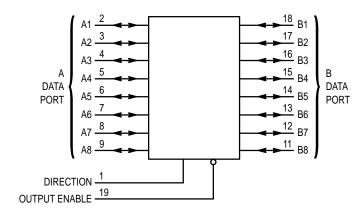
High-Performance Silicon-Gate CMOS

The MC54/74HC640A is identical in pinout to the LS640. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

The HC640A is a 3–state transceiver that is used for 2–way asynchronous communication between data buses. The device has an active–low Output Enable pin, which is used to place the I/O ports into high–impedance states. The Direction control determines whether data flows from A to B or from B to A.

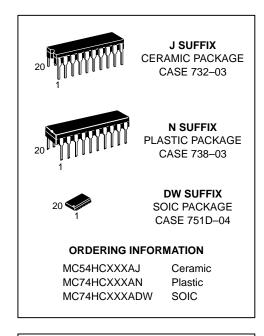
- · Output Drive Capability: 15 LSTTL Loads
- · Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2 to 6 V
- Low Input Current: 1 μA
- · High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- Chip Complexity: 276 FETs or 69 Equivalent Gates

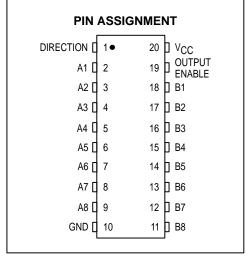
LOGIC DIAGRAM



PIN 10 = GND PIN 20 = V_{CC}

MC54/74HC640A





FUNCTION TABLE

Control Inputs		
Output Enable	Direction	Operation
L	L	Data Transmitted from Bus B to Bus A (Inverted)
L	Н	Data Transmitted from Bus A to Bus B (Inverted)
Н	Х	Buses Isolated (High–Impedance State)

X = don't care



MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
VCC	DC Supply Voltage (Referenced to GND)	- 0.5 to + 7.0	V
V _{in}	DC Input Voltage (Referenced to GND), Pin 1 or 19	- 1.5 to V _{CC} + 1.5	V
V _{I/O}	DC I/O Voltage (Referenced to GND)	-0.5 to V _{CC} + 0.5	V
l _{in}	DC Input Current, per Pin	± 20	mA
I _{I/O}	DC I/O Current, per Pin	± 35	mA
Icc	DC Supply Current, V _{CC} and GND Pins	± 75	mA
PD	Power Dissipation in Still Air, Plastic or Ceramic DIP† SOIC Package†	750 500	mW
T _{stg}	Storage Temperature	- 65 to + 150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package) (Ceramic DIP)	260 300	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND $\leq (V_{in}$ or $V_{out}) \leq V_{CC}$. Unused inputs must always be

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open. I/O pins must be connected to a properly terminated line or bus.

Ceramic DIP: – 10 mW/°C from 100° to 125°C

SOIC Package: - 7 mW/°C from 65° to 125°C

For high frequency or heavy load considerations, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
VCC	DC Supply Voltage (Referenced to GND)			6.0	V
V _{in} , V _{out}	DC Input Voltage, Output Voltage (Referenced to GND)			VCC	V
T _A	Operating Temperature, All Package Types		- 55	+ 125	°C
t _r , t _f	(Figure 1)	V _{CC} = 2.0 V V _{CC} = 4.5 V V _{CC} = 6.0 V	0 0 0	1000 500 400	ns

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

			Guaranteed Limit		mit		
Symbol	Parameter	Test Conditions	v _{CC}	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
VIH	Minimum High-Level Input Voltage	$V_{out} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$ $ I_{out} \le 20 \mu\text{A}$	2.0 4.5 6.0	1.5 3.15 4.2	1.5 3.15 4.2	1.5 3.15 4.2	V
V _{IL}	Maximum Low–Level Input Voltage	$V_{out} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$ $ I_{out} \le 20 \mu\text{A}$	2.0 4.5 6.0	0.3 0.9 1.2	0.3 0.9 1.2	0.3 0.9 1.2	V
VOH	Minimum High–Level Output Voltage	$V_{in} = V_{IH} \text{ or } V_{IL}$ $ I_{out} \le 20 \mu\text{A}$	2.0 4.5 6.0	1.9 4.4 5.9	1.9 4.4 5.9	1.9 4.4 5.9	V
		$V_{in} = V_{IH} \text{ or } V_{IL} I_{out} \le 6.0 \text{ mA} $ $ I_{out} \le 7.8 \text{ mA}$	4.5 6.0	3.98 5.48	3.84 5.34	3.70 5.20	
VOL	Maximum Low–Level Output Voltage	$V_{in} = V_{IH} \text{ or } V_{IL}$ $ I_{out} \le 20 \mu\text{A}$	2.0 4.5 6.0	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V
		$V_{in} = V_{IH} \text{ or } V_{IL} I_{out} \le 6.0 \text{ mA} $ $ I_{out} \le 7.8 \text{ mA}$	4.5 6.0	0.26 0.26	0.33 0.33	0.40 0.40	
l _{in}	Maximum Input Leakage Current	V _{in} = V _{CC} or GND, Pin 1 or 19	6.0	± 0.1	± 1.0	± 1.0	μΑ
loz	Maximum Three–State Leakage Current	Output in High-Impedance State $V_{in} = V_{IL}$ or V_{IH} $V_{out} = V_{CC}$ or GND	6.0	± 0.5	± 5.0	± 10	μА
lcc	Maximum Quiescent Supply Current (per Package)	$V_{in} = V_{CC}$ or GND $I_{out} = 0 \mu A$	6.0	4	40	160	μА

NOTE: Information on typical parametric values can be found in Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

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^{*} Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

[†]Derating — Plastic DIP: – 10 mW/°C from 65° to 125°C

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_f = t_f = 6 \text{ ns}$)

			Guaranteed Limit			
Symbol	Parameter	V _{CC}	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
t _{PLH} , t _{PHL}	Maximum Propagation Delay, A to B, B to A (Figures 1 and 3)	2.0 4.5 6.0	75 15 13	95 19 16	110 22 19	ns
t _{PLZ} , t _{PHZ}	Maximum Propagation Delay, Direction or Output Enable to A or B (Figures 2 and 4)	2.0 4.5 6.0	110 22 19	140 28 24	165 33 28	ns
tPZL, tPZH	Maximum Propagation Delay, Output Enable to A or B (Figures 2 and 4)	2.0 4.5 6.0	110 22 19	140 28 24	165 33 25	ns
tTLH, tTHL	Maximum Output Transition Time, Any Output (Figures 1 and 3)	2.0 4.5 6.0	60 12 10	75 15 13	90 18 15	ns
C _{in}	Maximum Input Capacitance, Pin 1 or 19	_	10	10	10	pF
C _{out}	Maximum Three–State I/O Capacitance (Output in High–Impedance State)	_	15	15	15	pF

NOTE: For propagation delays with loads other than 50 pF, and information on typical parametric values, see Chapter 2 of the Motorola High–Speed CMOS Data Book (DL129/D).

ſ			Typical @ 25°C, V _{CC} = 5.0 V		ĺ
ı	C_{PD}	Power Dissipation Capacitance (Per Transceiver Channel)*	40	pF	l

^{*} Used to determine the no–load dynamic power consumption: P_D = C_{PD} V_{CC}²f + I_{CC} V_{CC}. For load considerations, see Chapter 2 of the Motorola High–Speed CMOS Data Book (DL129/D).

SWITCHING WAVEFORMS

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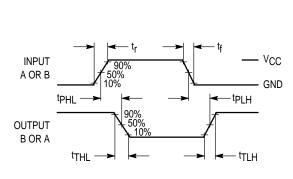


Figure 1.

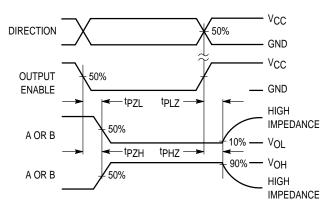
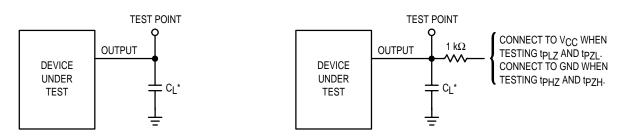


Figure 2.

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tTEST CIRCUITS

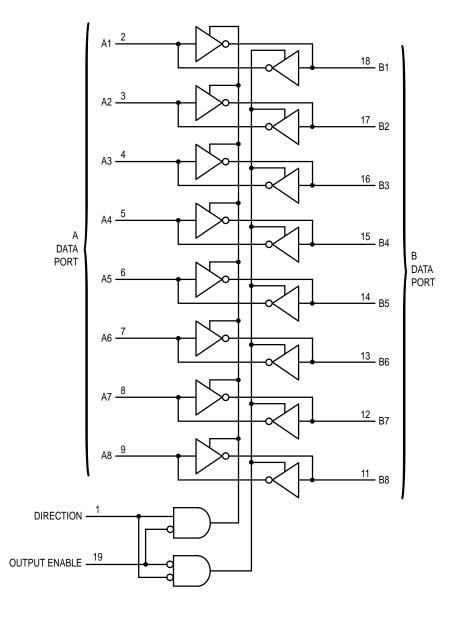


^{*} Includes all probe and jig capacitance

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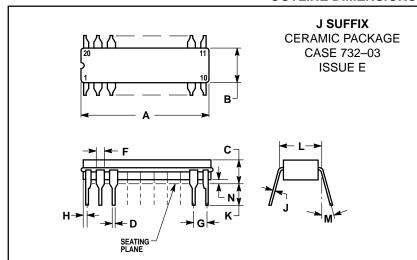
Figure 3. Figure 4.

EXPANDED LOGIC DIAGRAM



MOTOROLA 4

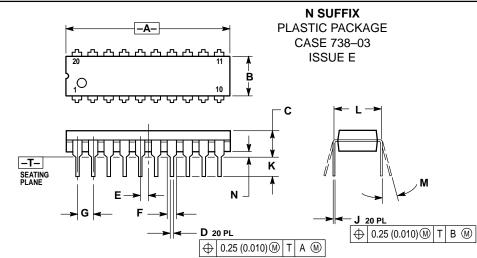
OUTLINE DIMENSIONS



- NOTES:

 1. LEADS WITHIN 0.25 (0.010) DIAMETER, TRUE
 POSITION AT SEATING PLANE, AT MAXIMUM
 MATERIAL CONDITION.
- 2. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 3. DIMENSIONS A AND B INCLUDE MENISCUS.

	MILLIN	METERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	23.88	25.15	0.940	0.990	
В	6.60	7.49	0.260	0.295	
O	3.81	5.08	0.150	0.200	
D	0.38	0.56	0.015	0.022	
F	1.40	1.65	0.055	0.065	
G	2.54 BSC		0.100 BSC		
Н	0.51	1.27	0.020	0.050	
ے	0.20	0.30	0.008	0.012	
Κ	3.18	4.06	0.125	0.160	
Г	7.62	BSC	0.300 BSC		
M	0 °	15°	0°	15°	
N	0.25	1.02	0.010	0.040	



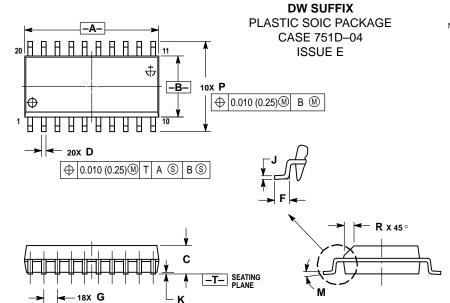
NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION L TO CENTER OF LEAD WHEN

- FORMED PARALLEL.

 4. DIMENSION B DOES NOT INCLUDE MOLD

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX		
Α	1.010	1.070	25.66	27.17
В	0.240	0.260	6.10	6.60
С	0.150	0.180	3.81	4.57
D	0.015	0.022	0.39	0.55
Е	0.050	BSC	1.27 BSC	
F	0.050	0.070	1.27	1.77
G	0.100	0.100 BSC		BSC
J	0.008	0.015	0.21	0.38
K	0.110	0.140	2.80	3.55
L	0.300 BSC		7.62	BSC
М	0°	15°	0°	15°
N	0.020	0.040	0.51	1.01



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- OTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

 4. MAXIMUM MOLD PROTRUSION 0.150

- (0.006) PER SIDE.

 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	12.65	12.95	0.499	0.510	
В	7.40	7.60	0.292	0.299	
С	2.35	2.65	0.093	0.104	
D	0.35	0.49	0.014	0.019	
F	0.50	0.90	0.020	0.035	
G	1.27	BSC	0.050 BSC		
J	0.25	0.32	0.010	0.012	
K	0.10	0.25	0.004	0.009	
M	0 °	7 °	0 °	7°	
Р	10.05	10.55	0.395	0.415	
R	0.25	0.75	0.010	0.029	

MC54/74HC640A

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